Listing of Claims:

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This listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently amended) A semiconductor wafer holding system for holding wafers in position within a transfer chamber during transfer of the wafers between <u>an</u> ambient atmosphere and an inspection chamber which is at vacuum pressure, comprising:

a transfer chamber interposed between the ambient atmosphere and the inspection chamber and subjected to alternating depressurization and repressurization;

at least one paddle fixedly arranged in said transfer chamber, and having a waferreceiving surface with openings therein adapted to be covered by a wafer; and

drawing means for drawing the wafer to said wafer-receiving surface of said at least one paddle to thereby inhibit motion of the wafer in said transfer chamber during at least one of the alternating depressurization and repressurization[[.]];

wherein said at least one paddle comprises two paddles.

- 2. (Original) The system of claim 1, wherein said drawing means are arranged to provide a pressure at said openings which is lower than pressure prevailing in said transfer chamber.
- 3. (Original) The system of claim 1, wherein said drawing means comprise a vacuum source or pump, and conduit means for providing flow communication between said vacuum source or pump and said openings to create suction thereat.

- 4. (Original) The system of claim 3, wherein said drawing means further comprise valve means operatively arranged with said conduit means for opening and closing the flow communication between said vacuum source or pump and said openings.
- 5. (Original) The system of claim 4, wherein said conduit means comprise a respective conduit leading to each of said at least one paddle, and said valve means comprise a respective valve operatively arranged with each said conduit.
- 6. (Original) The system of claim 5, wherein said valve means includes a flow connection to an interior of said transfer chamber to controllably communicate said openings with the interior of said transfer chamber.
- 7. (Original) The system of claim 5, wherein said drawing means further comprise paddle conduits arranged in each of said at least one paddle in flow communication with said openings in said paddle.

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9. (Currently amended) The system of claim [[8]] 1, wherein said drawing means comprise a vacuum source or pump, paddle conduits arranged in each of said paddles, first and second branch conduits each arranged between said vacuum source or pump and said paddle conduits in a respective one of said first and second paddles, and first and second valves operatively arranged with a respective one of said first and second branch conduits for opening

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and closing flow communication between said vacuum source or pump and said openings in the respective one of said first and second paddles.

- 10. (Withdrawn) The system of claim 1, further comprising laminar flow means for introducing a laminar flow of gas into said transfer chamber to repressurize said transfer chamber.
- 11. (Withdrawn) The system of claim 10, wherein said laminar flow means comprise a diffuser arranged in said transfer chamber and having at least one opening through which the gas is introduced into said transfer chamber.
- 12. (Currently amended) The system of claim 1, further comprising valves for sealing said transfer chamber from the ambient atmosphere and the inspection chamber during the alternating depressurization and repressurization of said transfer chamber.

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- 20. (Withdrawn) The method of claim 17, further comprising introducing a laminar flow of gas into the transfer chamber during repressurization of the transfer chamber.
- 21. (Withdrawn) The method of claim 20, wherein the step of introducing gas into the transfer chamber comprises arranging a diffuser in the transfer chamber and providing the diffuser with at least one opening through which the gas is introduced into the transfer chamber.

22. (Original) A method for transferring semiconductor wafers between ambient atmosphere and an inspection chamber, maintained at a vacuum pressure, through a transfer chamber, comprising:

transferring a wafer from the ambient atmosphere through a first gate valve onto a paddle in the transfer chamber while the transfer chamber is isolated from the inspection chamber by a closed second gate valve;

closing the first gate valve to isolate the transfer chamber from the ambient atmosphere after the first wafer has been placed onto the paddle;

depressurizing the transfer chamber until the pressure in the transfer chamber is near the pressure in the inspection chamber, and then opening the second gate valve;

transferring the wafer from the transfer chamber to the inspection chamber after the second gate valve is open;

inspecting the wafer and then returning the inspected wafer to the paddle in the depressurized transfer chamber;

closing the second gate valve and, while the second gate valve is closed, repressurizing the transfer chamber;

providing the paddle with a wafer-receiving surface having openings therein, the wafer being placed on the paddle and over the openings therein;

coupling the openings in flow communication with a vacuum source or pump; and controlling the flow communication between the vacuum source or pump and the openings during at least one of the depressurization and repressurization of the transfer chamber to cause the wafer to be drawn to the wafer-receiving surface of the paddle by suction and

thereby inhibit motion of the wafer during said at least one of the depressurization and repressurization of the transfer chamber.

- 23. (Original) The method of claim 22, wherein said coupling of the openings to a vacuum source or pump comprises providing a conduit between the vacuum source or pump, and the step of controlling flow communication between the vacuum source or pump and the openings comprises operatively arranging a valve with the conduit.
- 24. (Original) The method of claim 22, further comprising the step of stopping the flow communication between the vacuum source or pump and the openings when the pressure in the depressurized transfer chamber rises to near atmospheric pressure.
- 25. (Original) The method of claim 24, further comprising the step of enabling flow communication between an interior of the transfer chamber and the openings as the flow communication between the vacuum source or pump and the openings is stopped.
- 26. (Original) The method of claim 22, wherein the step of repressurizing the transfer chamber comprises the step of introducing a laminar flow of gas into the transfer chamber.
- 27. (Original) A method for transferring semiconductor wafers between ambient atmosphere and an inspection chamber, maintained at a vacuum pressure, through a transfer chamber, comprising:

transferring a first wafer from the ambient atmosphere through a first gate valve onto a first paddle in the transfer chamber while the transfer chamber is isolated from the inspection chamber by a closed second gate valve;

closing the first gate valve to isolate the transfer chamber from the ambient atmosphere after the first wafer has been placed onto the paddle;

depressurizing the transfer chamber until the pressure in the transfer chamber is near the pressure in the inspection chamber, and then opening the second gate valve;

transferring the first wafer from the transfer chamber to the inspection chamber after the second gate valve is open;

closing the second gate valve and, while the second gate valve is closed, placing the first wafer onto a measurement site in the inspection chamber, repressurizing the transfer chamber, opening the first gate valve, placing a second wafer onto a second paddle in the transfer chamber, closing the first gate valve and depressurizing the transfer chamber;

opening the second gate valve and, while the second gate valve is open, transferring the first wafer from the inspection chamber onto the first paddle in the transfer chamber, and transferring the second wafer from the transfer chamber to the inspection chamber;

closing the second gate valve and, while the second gate valve is closed, placing the second wafer onto a measurement site in the inspection chamber, repressurizing the transfer chamber, opening the first gate valve, placing a third wafer onto the first paddle in the transfer chamber, closing the first gate valve and depressurizing the transfer chamber;

providing the first and second paddles with a wafer-receiving surface having openings therein, the wafers being placed on the first and second paddles, and over the openings; coupling the openings in flow communication with a vacuum source or pump; and

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controlling the flow communication between the vacuum source or pump and the openings during at least one of the depressurization and repressurization of the transfer chamber to cause the wafer to be drawn to the wafer-receiving surface of the paddle by suction and thereby inhibit motion of the wafer during said at least one of the depressurization and repressurization of the transfer chamber.

- 28. (Original) The method of claim 27, wherein said coupling of the openings to a vacuum source or pump comprises providing a conduit between the vacuum source or pump, and the step of controlling flow communication between the vacuum source or pump and the openings comprises operatively arranging a valve with the conduit.
- 29. (Original) The method of claim 27, further comprising the step of stopping the flow communication between the vacuum source or pump and the openings when the pressure in the depressurized transfer chamber rises to near atmospheric pressure.
- 30. (Original) The method of claim 29, further comprising the step of enabling flow communication between an interior of the transfer chamber and the openings as the flow communication between the vacuum source or pump and the openings is stopped.
- 31. (Original) The method of claim 27, wherein the step of depressurizing the transfer chamber comprises the steps of opening a roughing valve operatively associated with the transfer chamber for depressurizing the chamber, measuring the pressure in the transfer chamber during depressurization and, when the measured pressure approaches 10E-3 Torr, closing the roughing

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valve and opening a turbo molecular vacuum pump to depressurize the transfer chamber to a pressure of about 10E-6 Torr.

32. (Original) The method of claim 31, further comprising the steps of:

enabling flow communication between the vacuum source or pump and the openings until the pressure in the depressurized transfer chamber rises to near atmospheric pressure pressure; and then

enabling flow communication between an interior of the transfer chamber and the openings.

33. (Original) The method of claim 27, wherein the step of repressurizing the transfer chamber comprises the step of introducing a laminar flow of gas into the transfer chamber.

34. (Original) The method of claim 33, wherein the step of introducing gas into the transfer chamber comprises the steps of operatively arranging a diffuser in the transfer chamber, and providing the diffuser with at least one opening through which the gas is introduced into the transfer chamber.

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